

**BCN1043**

# **COMPUTER ARCHITECTURE & ORGANIZATION**

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CAO – Chapter 5 – P1. Mritha Ramalingam

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**Faculty of Computer Systems & Software Engineering**

# LEARNING OUTCOMES

- Able to identify the main types of memory technology (e.g., SRAM, DRAM, Flash, magnetic disk) and their relative cost and performance.
- Able to describe the principles of memory management and how the use of memory hierarchy (cache, virtual memory) is used to reduce the effective memory latency.
- Able to describe the reason for and use of cache memory
- Able to explain the effect of memory latency on running time.

# COMPUTER MEMORY

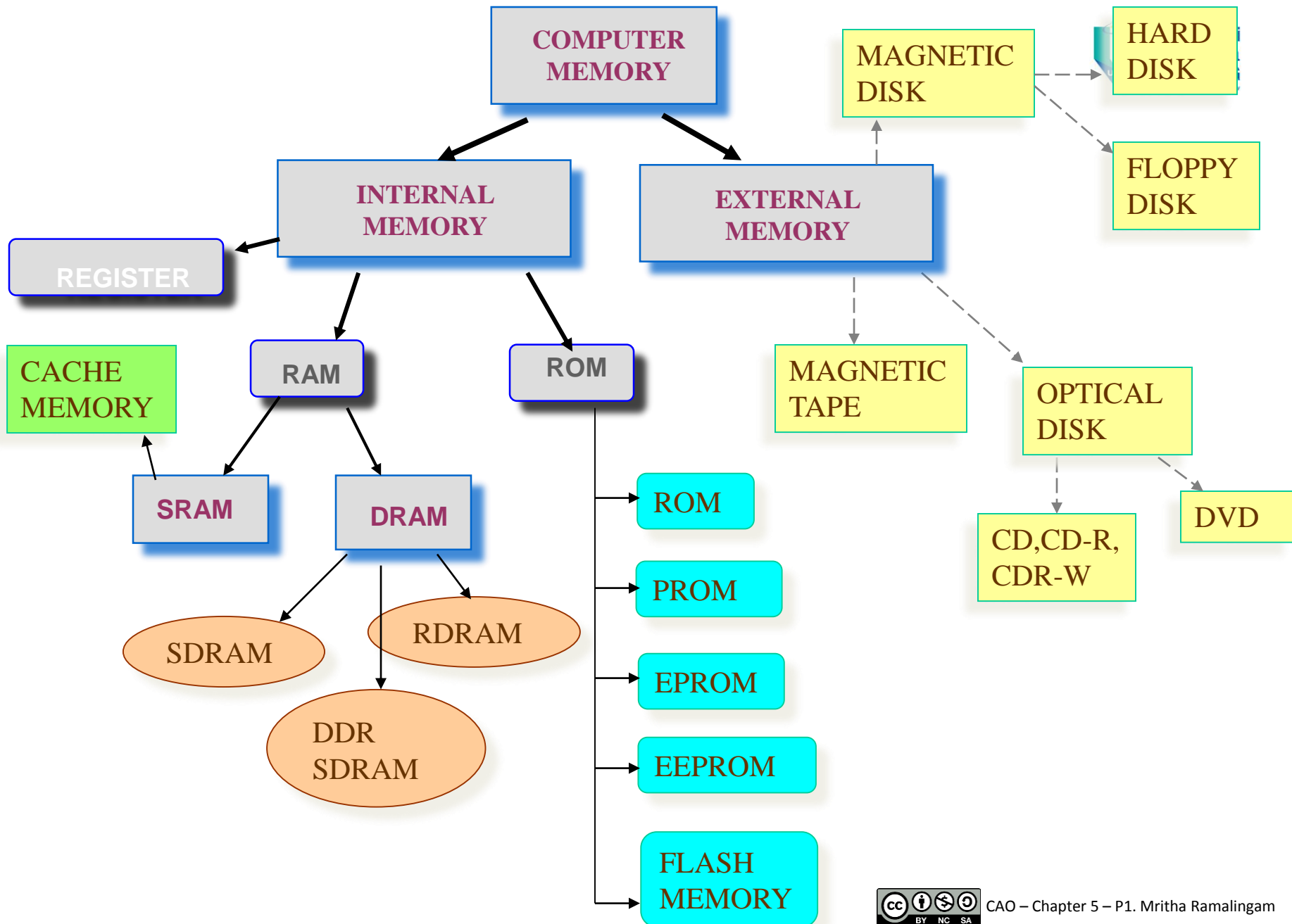
1. Storage System & Technology
2. Memory Hierarchy
3. Memory Organization and Operations
4. Cache Memories



# Storage System & Technology

1. **Location**
2. **Capacity**
3. **Unit of Transfer**
4. **Access method**
5. **Performance**
6. **Physical type**
7. **Physical characteristics**
8. **Organization**





# Storage System & Technology

**1.Location:** Based on location, memory can be classified as

- CPU memory
- Internal memory
- External memory

**2.Capacity:** Based on the amount of data that can be stored in memory

- 1.Word
- 2.bytes

**3.Unit of transfer:** number of bits per time period

## 4. Based on **Access Method**

### 1. Random access:

- Each location - unique physical address
- Any order access
- E.g main memory

### 2. Sequential access:

- no unique address
- Read in a sequence
- High variable Access times
- E.g tape drive



### 3. Direct access

- unique addresses
- E.g disk drives

### 4. Associative access

- A variation of RAM
- Accessing based on their contents instead of their location
  - highly fast
- E.g few cache memory

## 5. Performance

- Access time
- Memory cycle time
- Transfer rate

## 6. Physical Type

- Semiconductor memory or RAM
- Magnetic Disk & Tape
- Optical disk

## 7. Physical Characteristics

- Volatile and non-volatile
- Erasable and nonerasable

## 8. Organisation

- Physical arrangement of bits to form words

# Random Access Memory - RAM

- **SRAM** (Static RAM) and **DRAM** (Dynamic RAM).
- **Static RAM (SRAM)** holds its data without external refresh, as long as electricity is supplied to the circuit.
- **Dynamic RAM (DRAM)** must be refreshed many times per second in order to hold its data contents.
- Strength of SRAMs:
  - **Simplicity:** SRAMs don't require external refresh circuitry or other work in order for them to keep their data intact.
  - **Speed:** SRAM is faster than DRAM.
- Weakness of SRAMs:
  - **Cost:** SRAM is, byte for byte, several times more expensive than DRAM.
  - **Size:** SRAMs take up much more space than DRAMs (which is part of why the cost is higher).

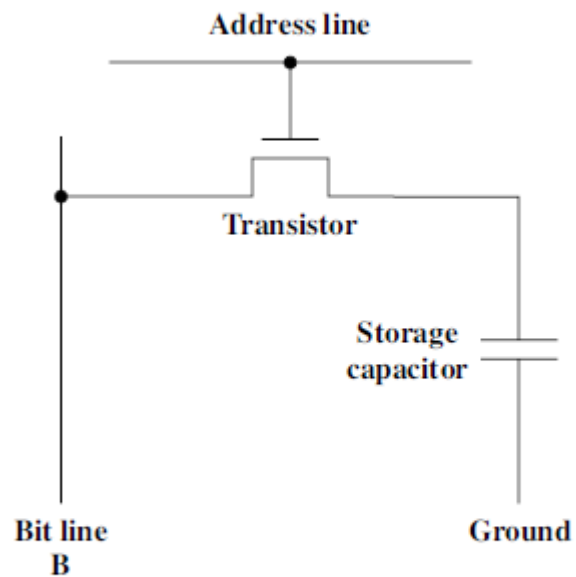
# DRAM vs. SRAM

## Dynamic RAM

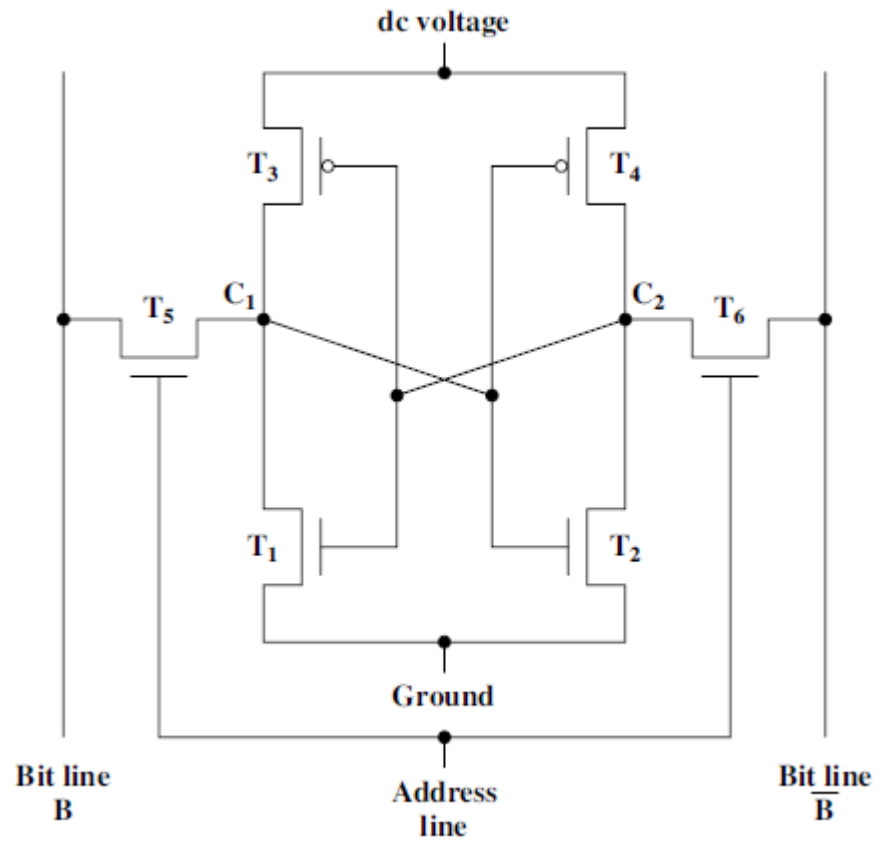
- Bits stored as charge in capacitors
- Charges leak
- Need refreshing even when powered
- Simpler construction
- More dense (smaller cell-more cell per unit area)
- Less expensive
- Need refresh circuits
- Slower access time
- Low power
- Application: Main memory

## Static RAM

- Bits stored as on/off switches
- No charges to leak
- No refreshing needed when powered
- More complex construction
- Less dense (less cell per unit area)
- More expensive
- Does not need refresh circuits
- Faster access time
- Consumes more power
- Application: Cache memory



(a) Dynamic RAM (DRAM) cell

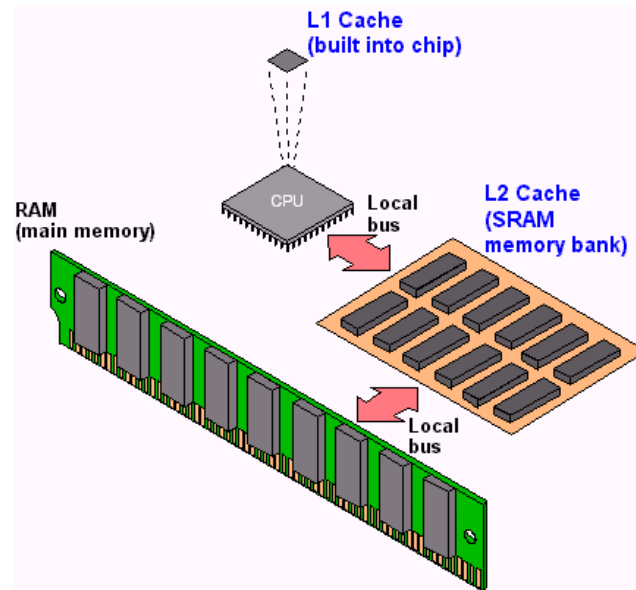


(b) Static RAM (SRAM) cell

# RAM (cont...)

- DRAM is used for system memory.
- SRAMs are used for level 1 cache and level 2 cache memory, for which it is perfectly suited (as the cache memory needs to be very fast, and not very large).

From Computer Desktop Encyclopedia  
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# Read-only memory - ROM

- There are five basic ROM types:
  - Read-only memory (ROM)
  - Programmable ROM (PROM)
  - Erasable PROM (EPROM)
  - Electrically EPROM (EEPROM)
  - Flash memory
- Each type has unique characteristics, but they have two things in common:
  - **nonvolatile** → it is not lost when electricity is removed.
  - Data stored in these chips is either **unchangeable** or requires a special operation to change (unlike RAM, which can be changed as easily as it is read).



# ROM (cont...)

- **ROM** - cannot reprogram or rewrite. Creating ROM chips is time-consuming and very expensive in small quantities.
- **PROM** - can be written once. chips can be bought inexpensively and coded using a special tool called a **programmer**.
- **EPROM** - can be rewritten many times. Erasable using ultraviolet (UV) light.
- **EEPROM**
  - Changing the contents does not require additional dedicated equipment.

# ROM (cont...)

- Electric field can return the electrons in the cells of an EEPROM to normal. This erases the targeted cells of the EEPROM, which can then be rewritten. EEPROMs are changed 1 byte at a time, which makes them versatile but slow.
- Hence, **Flash memory**, a type of EEPROM that uses **in-circuit wiring** to erase by applying an electrical field to the entire chip or to predetermined sections of the chip called **blocks**. Flash memory works much faster than traditional EEPROMs because it writes data in chunks, usually 512 bytes in size, instead of 1 byte at a time.

- **Characteristics of ROM**

- Permanent type of memory storage.
- It is nonvolatile. (Data will not lose if the power is turn off)
- Data stored in ROM is either unchangeable or required a special operation to change it.
- Example of application in computer: BIOS

- **Types of ROM**

- ROM
- PROM
- EPROM
- EEPROM
- Flash Memory

## ➤ ROMs

- ➔ Data is “wired in” during fabrication at a chip manufacturer’s plant
- ➔ Permanent pattern of data that cannot be change.
- ➔ Not possible to write new data into it.

## ➤ PROMs

- ➔ Programmable ROM
- ➔ Data can be written once by the user employing a PROM programmer
- ➔ Useful for small production runs

## ➤ EPROM

- ➔ Erasable PROM
- ➔ Programming is similar to a PROM
- ➔ Can be rewritten many times.
- ➔ Erase using ultraviolet (UV) light.

- EEPROM
  - Electrically erasable PROMs - Its contents are erased by applying a specific electrical voltage
  - Can be written to many times while remaining in a system
  - Does not have to be erased first
  - Program and erase by individual bytes
  - Used in systems for development, personalization, and other tasks requiring unique information to be stored
- Flash Memory
  - Similar to EEPROM in using electrical erase
  - Fast erasures, erase by block
  - Higher density than EEPROM

# Magnetic Disk

- The disk is a circular platter constructed of nonmagnetic material called the substrate, coated with magnetizable material.
- Data is recorded onto and later read from the disk using a conducting coil, the head.
- Substrate used to be aluminium.
- Now glass
  - Improved surface uniformity
    - Increases reliability
  - Reduction in surface defects
    - Reduced read/write errors
  - Better stiffness (maintain data)
  - Better shock/damage resistance (avoid surface damage)

# Physical Characteristics

- Fixed(rare) or movable head
- Removable or fixed
- Single or double (usually) sided
- Single or multiple platter

## Fixed/Movable Head Disk

### Fixed head

- One read write head per track
- Heads mounted on fixed ridged arm

### Movable head

- One read write head per side
- Mounted on a movable arm

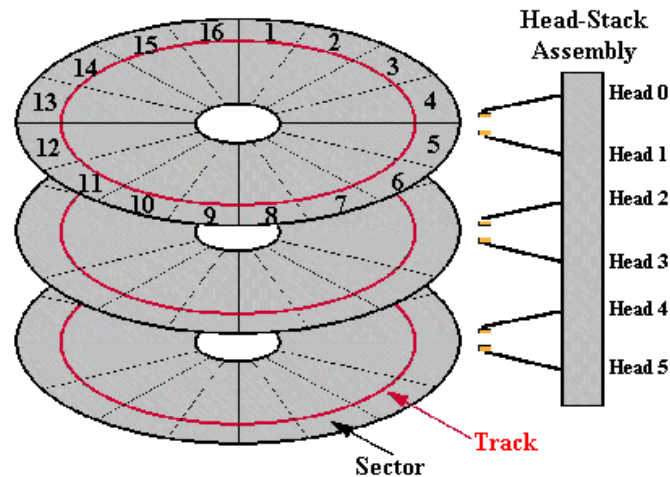
## Multiple platter

- One head per side
- Heads are joined and aligned
- Aligned tracks on each platter form cylinders
- Data is striped by cylinder
  - ➔ reduces head movement
  - ➔ Increases speed (transfer rate)

# Disk Performance Parameters

- Seek time - the time it takes to position the head at the right track
- Rotational delay - the time it takes for the beginning of the sector to reach the head
- Access time - the sum of the seek time and rotational delay
- Transfer time - time to read the block (sector) from the disk and transfer it to main memory

Drive Physical and Logical Organization



Source: <http://img.watchstor.com>



# HOW HARD DRIVES WORK



# Optical Disk

- Data is stored on an optical medium (such as CD-ROM or DVD), and read with a laser beam.
- It's not practical for use in computer processing, but it is an ideal solution for storing large quantities of data very inexpensively, and more importantly, transporting that data between computer devices.
- Optical disk products:
  - CD-ROM (Compact disk read-only memory)
  - CD-R (CD Recordable)
  - CD-RW (CD Rewritable)
  - DVD (Digital Versatile Disk)

# CD-ROM

- Originally for audio
- 650Mbytes giving over 70 minutes audio
- Polycarbonate coated with highly reflective coat, usually aluminum
- Data stored as pits and bumps
- Read by reflecting laser
- Constant packing density
- Constant linear velocity

## CD-Writable

- WORM (Write Once, Read Many disks)
- Now affordable
- Compatible with CD-ROM drives

## CD-RW

- Erasable
- Getting cheaper
- Mostly CD-ROM drive compatible

## DVD

- Digital Versatile Disk
  - Will read computer disks and play video disks
- Multi-layer
- Very high capacity (4.7G per layer)
- Full length movie on single disk
  - Using MPEG compression
- Finally standardized
- Movies carry regional coding
- Players only play correct region films
- Can be “fixed”

# MAGNETIC TAPE

- Use the same reading and recording techniques as magnetic disk system.
- Data on the tape are structured as a number of parallel tracks running lengthwise.
  - The first kind of secondary memory
  - Still widely used
    - very cheap
    - very slow
  - Sequential access
    - Data is organized as records with physical air gaps between records
    - One words is stored across the width of the tape and read using multiple read/write heads

# Chapter 5

Chapter 5 will continue!

